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Hyperfast Rectifier, 20 A FRED Pt[®] G5



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS									
I _{F(AV)}	20 A								
V _R	600 V								
V _F at I _F at 125 °C	1.40 V								
t _{rr} (typ.)	19 ns								
T _J max.	175 °C								
Package	D ² PAK 2L (TO-263AB 2L)								
Circuit configuration	Single								

FEATURES

- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV battery charging stations and high frequency stages of UPS applications

MECHANICAL DATA

Case: D²PAK 2L (TO-263AB 2L)

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Repetitive peak reverse voltage	V _{RRM}		600	V						
Average rectified forward current	I _{F(AV)}	T _C = 107 °C, D = 0.50	20							
Repetitive peak forward current	I _{FRM}	T _C = 107 °C, D = 0.50, f = 20 kHz	40	A						
Non-repetitive peak surge current	I _{FSM}	T_{C} = 25 °C, t_{p} = 10 ms, sine wave	185							
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C						

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)										
PARAMETERSYMBOLTEST CONDITIONSMIN.TYP.MAX.										
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-					
	V _F	I _F = 20 A	-	1.7	2.31	V				
Forward voltage		I _F = 20 A, T _J = 125 °C	-	1.40	-					
Poweree leekage eurrent	I _R	$V_{R} = V_{R}$ rated	-	-	10					
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA				
Junction capacitance	CT	V _R = 200 V	-	25	-	pF				
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH				

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 1
 Document Number: 97027

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COMPLIANT

VS-E5TX2106S2L-M3



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST	CONDITIONS	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1.0 \text{ A,d}I_F/c$	I _F = 1.0 A,dI _F /dt = 100 A/µs, V _R = 30 V			-				
Reverse recovery time	t _{rr}	T _J = 25 °C		-	33	-	ns			
		T _J = 125 °C		-	43	-				
Peak recovery current		T _J = 25 °C	l _F = 12 A dl _F /dt = 1000 A/µs	-	12	-	A			
	I _{RRM}	T _J = 125 °C	di _F /dt = 1000 A/μs V _R = 400 V	-	20	-				
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	185	-	nC			
Reverse recovery charge		T _J = 125 °C		-	510	-				
Reverse recovery time	t _{rr}	T _J = 25 °C		-	41	-	ns			
neverse recovery time		T _J = 125 °C		-	50	-				
Pool recovery ourrent	I _{RRM}	T _J = 25 °C	l _F = 20 A dl _F /dt = 1000 A/μs	-	12	-	A nC			
Peak recovery current		T _J = 125 °C	$V_{\rm R} = 400 \text{ V}$	-	19	-				
		T _J = 25 °C		-	240	-				
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	640	-				

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Thermal resistance, junction-to-case	R _{thJC}		-	-	1.72	°C/W				
Weight			-	2.0	-	g				
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C				
Marking device		Case style D ² PAK 2L (TO-263AB 2L)	E5TX2106S							

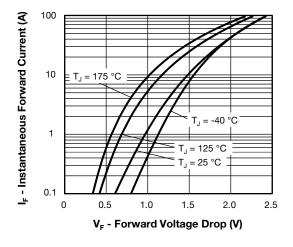


Fig. 1 - Forward Voltage Drop Characteristics

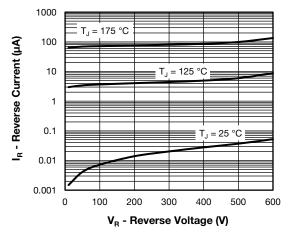
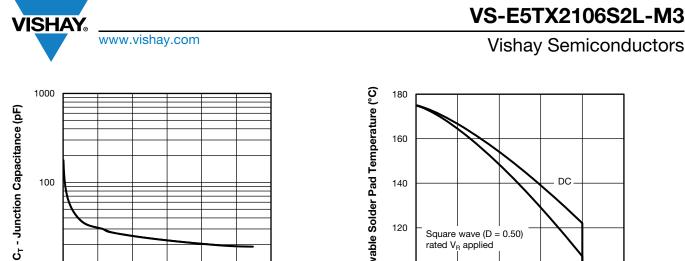


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



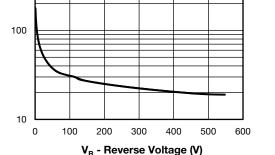


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

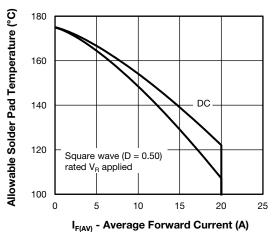


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

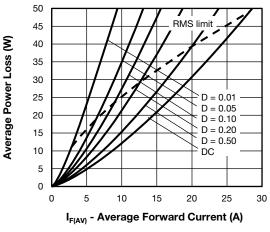


Fig. 5 - Forward Power Loss Characteristics

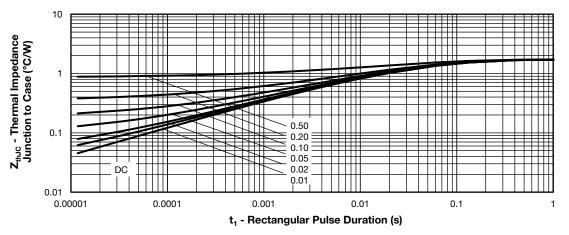


Fig. 6 - Transient Thermal Impedance, Junction to Case

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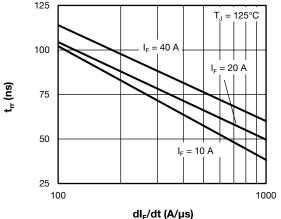


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

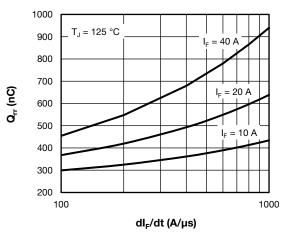


Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt

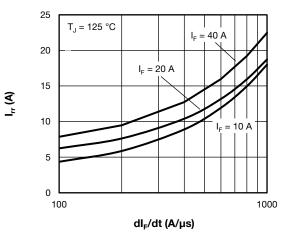


Fig. 9 - Typical Reverse Recovery Current vs. dl_F/dt

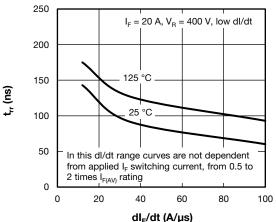


Fig. 10 - Typical Reverse Recovery Time vs. dl_F/dt

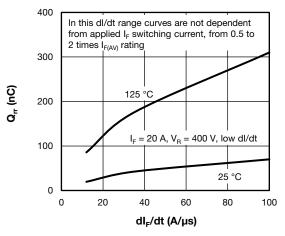


Fig. 11 - Typical Reverse Recovery Charge vs. dl_F/dt

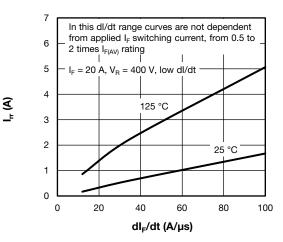


Fig. 12 - Typical Reverse Recovery Current vs. dl_F/dt

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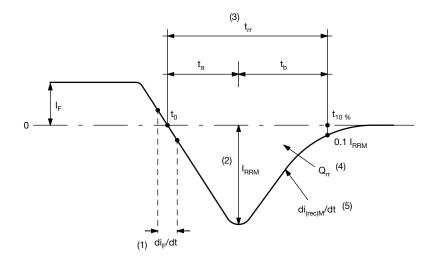


Fig. 13 - Reverse Recovery Waveform and Definitions

Notes

- $^{(1)}$ di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- $^{(3)}$ t_{rr} reverse recovery time measured from t₀, crossing point of negative going I_F, to point t_{10%}, 0.1 I_{RRM}
- $^{(4)}~~\text{Q}_{rr}$ area under curve defined by t_0 and $t_{10~\%}$

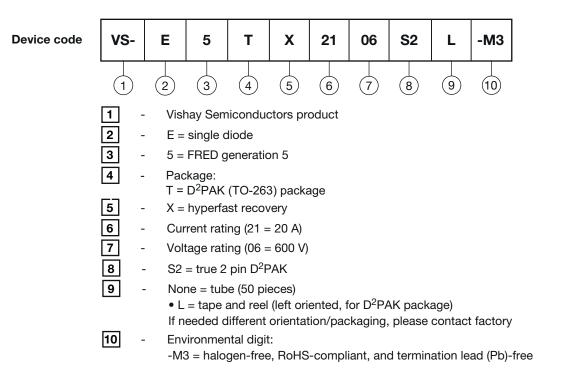
$$Q_{rr} = \int_{t_0}^{t_{10}\%} I(t)dt$$

 $^{(5)}$ di_{(rec)}M/dt - peak rate of change of current during t_{b} portion of t_{rr}



ORDERING INFORMATION TABLE

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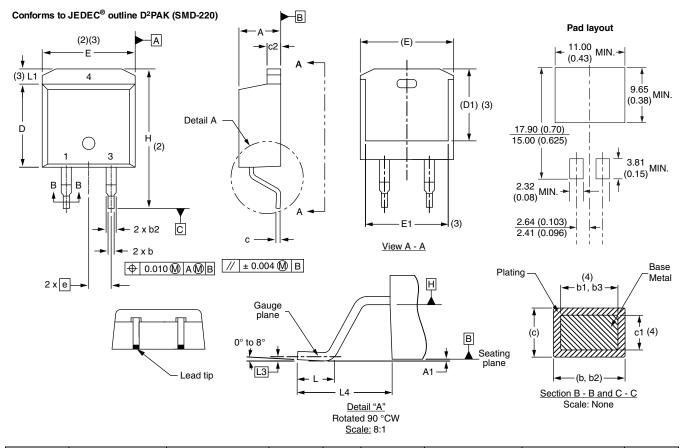
ORDERING INFORMATION (Example)								
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-E5TX2106S2L-M3	800	13" diameter reel						

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?96683
Part marking information	www.vishay.com/doc?96693
Packaging information	www.vishay.com/doc?95032



D²PAK 2L (TO-263AB 2L)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	ETERS	INC	HES	NOTES	NOTES	SYMBOL		SYMBOL MILLIMETERS		INCHES			
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES		
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3		
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3		
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3		
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC			
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625			
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110			
с	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3		
c1	0.38	0.58	0.015	0.023	4		L3	0.25 BSC		L3 0.25 BSC		0.010	BSC	
c2	1.14	1.65	0.045	0.065			L4	4.78	5.28	0.188	0.208			
D	8.51	9.65	0.335	0.380	2									

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
 (3) Thermal and contain antional within dimension E 1.1, D1 and E1.

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

(7) Outline conforms to JEDEC® outline TO-263AB

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